GR PSLM31.23

DURIS® S 5







Applications

Architecture / Garden Lighting (LED & Laser)Mood Lighting

Features:

- Package: white SMT package, colorless clear resin

- Typ. Radiation: 120° (Lambertian emitter)

- Lumen maintenance: LM-80-15 in Progress

- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)

- Luminous Flux: typ. 17 lm

- Luminous efficacy: typ. 81 lm/W



Ordering Information			
Туре	Luminous Flux 1) $I_F = 100 \text{ mA}$ Φ_V	Ordering Code	
GR PSLM31.23-FTGP-46-1	15 19 lm	Q65112A4967	



GR PSLM31.23

Maximum Ratings			
Parameter	Symbol		Values
Operating Temperature	T _{op}	min.	-40 °C
	οp	max.	100 °C
Storage Temperature	T _{stg}	min.	-40 °C
	3.69	max.	100 °C
Junction Temperature	T _j	max.	125 °C
Forward current	I _E	min.	10 mA
	·	max.	200 mA
Surge Current	I _{FS}	max.	300 mA
$t \le 10 \mu\text{s}; \text{ D} = 0.005 ; \text{ T}_{J} = 25 ^{\circ}\text{C}$			
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	V_{ESD}		2 kV



Characteristics

 $I_{\rm F} = 100 \, \text{mA}; \, T_{\rm J} = 25 \, ^{\circ}\text{C}$

F 100 1117 (, 1) 20 0			
Parameter	Symbol		Values
Dominant Wavelength ²⁾ I _F = 100 mA	$\lambda_{\sf dom}$	min. typ. max.	620 nm 623 nm 630 nm
Viewing angle at 50% I _v	2φ	typ.	120 °
Forward Voltage ³⁾ I _F = 100 mA	V _F	min. typ. max.	1.80 V 2.11 V 2.40 V
Electrical thermal resistance junction/solderpoint with efficiency $\eta_{\rm e}$ = 38.9 %	$R_{\text{thJS elec.}}$	typ.	15 K / W



Brightness Groups

Group	Luminous Flux ¹⁾ $I_{F} = 100 \text{ mA}$ min. Φ_{V}	Luminous Flux ¹⁾ $I_{F} = 100 \text{ mA}$ $max.$ Φ_{V}	
FT	15 lm	16 lm	
FU	16 lm	18 lm	
GP	18 lm	19 lm	

Forward Voltage Groups

Group	Forward Voltage ³⁾ I _F = 100 mA min. V _F	Forward Voltage 3) I _F = 100 mA max. V _F	
F	1.80 V	2.00 V	
G	2.00 V	2.20 V	
Н	2.20 V	2.40 V	

Wavelength Groups

Group	Dominant Wavelength 2)	Dominant Wavelength 2)		
	$I_{F} = 100 \text{ mA}$	$I_{F} = 100 \text{ mA}$		
	min.	max.		
	$\lambda_{\sf dom}$	λ_{dom}		
4	620 nm	624 nm		
5	624 nm	627 nm		
6	627 nm	630 nm		



Group Name on Label

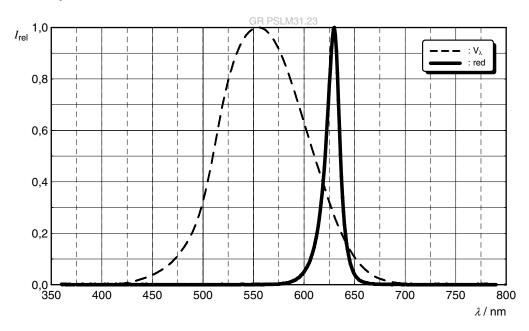
Example: FT-4-F

Brightness	Wavelength	Forward Voltage
FT	4	F



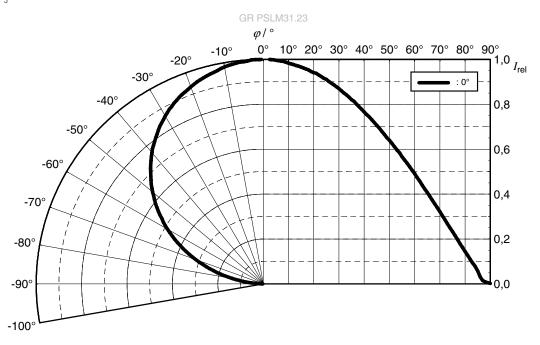
Relative Spectral Emission 4)

 $I_{rel} = f(\lambda); I_F = 100 \text{ mA}; T_J = 25 ^{\circ}\text{C}$



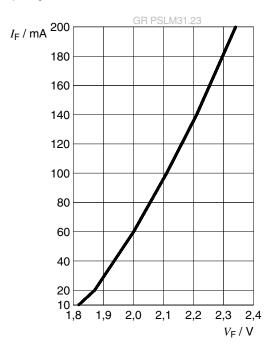
Radiation Characteristics 4)

 $I_{rel} = f(\phi); T_J = 25 °C$



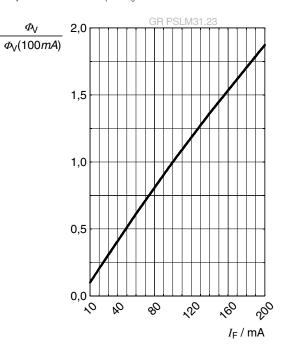
Forward current 4), 5)

$$I_F = f(V_F); T_J = 25 \, ^{\circ}C$$



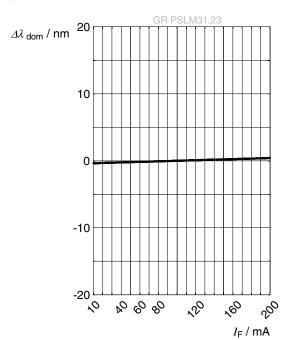
Relative Luminous Flux 4), 5)

$$\Phi_{V}/\Phi_{V}(100 \text{ mA}) = f(I_{F}); T_{J} = 25 \text{ }^{\circ}\text{C}$$



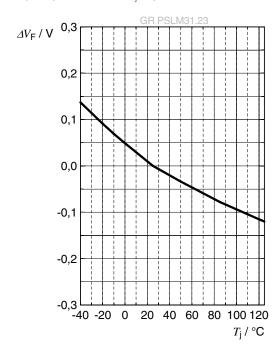
Dominant Wavelength 4)

$$\Delta\lambda_{dom} = f(I_F); T_J = 25 \text{ }^{\circ}\text{C}$$



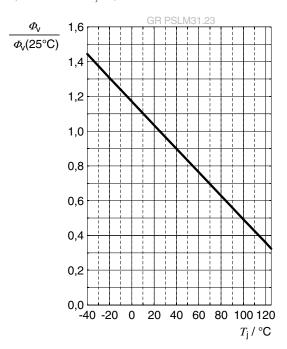
Forward Voltage 4)

$$\Delta V_{_F} = V_{_F} - V_{_F} (25 \ ^{\circ}C) = f(T_{_j}); \ I_{_F} = 100 \ mA$$



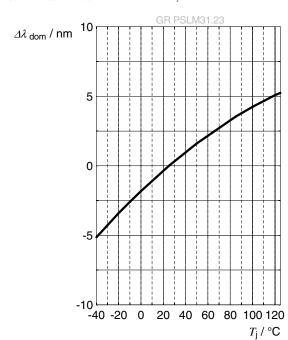
Relative Luminous Flux 4)

$$\Phi_{V}/\Phi_{V}(25 \text{ °C}) = f(T_{j}); I_{F} = 100 \text{ mA}$$



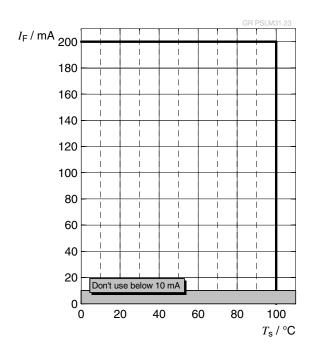
Dominant Wavelength 4)

$$\Delta\lambda_{dom} = \lambda_{dom} - \lambda_{dom}(25 \ ^{\circ}C) = f(T_{j}); \ I_{F} = 100 \ mA$$



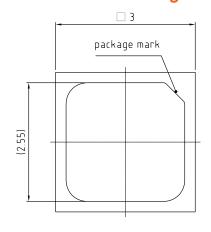
Max. Permissible Forward Current

 $I_F = f(T)$

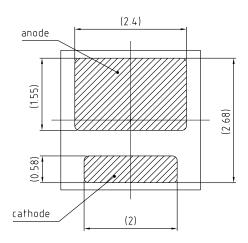




Dimensional Drawing 6)







general tolerance ±0.1 lead finish Ag

C67062-A0223-A2..-03

Further Information:

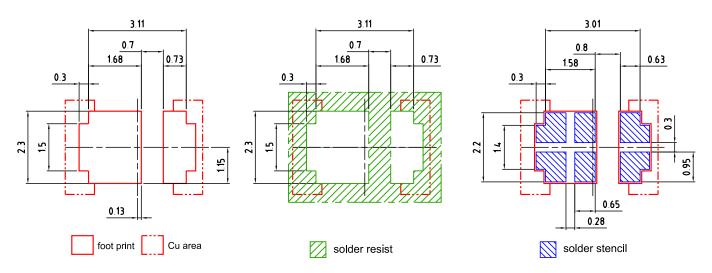
Approximate Weight: 17.7 mg

Package marking: Anode

ESD advice: The device is protected by ESD device which is connected in parallel to the

Chip.

Recommended Solder Pad 6)



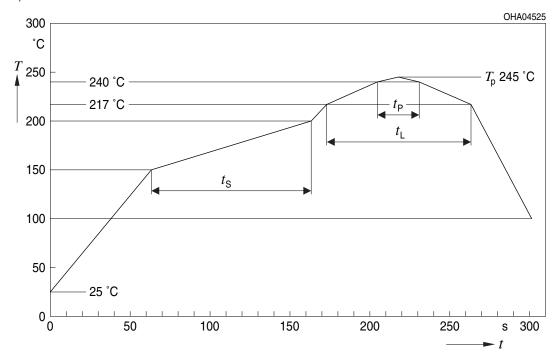
E062.3010.142 -05

For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for ultra sonic cleaning.



Reflow Soldering Profile

Product complies to MSL Level 3 acc. to JEDEC J-STD-020E



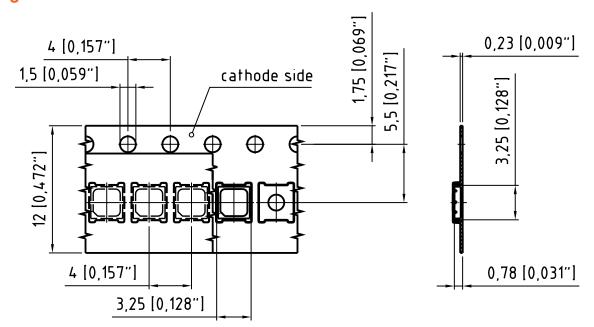
Profile Feature Symbol Pb-Free (SnAgCu) Asser			sembly	Unit	
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*)			2	3	K/s
25 °C to 150 °C					
Time t _s	t_s	60	100	120	S
T_{Smin} to T_{Smax}					
Ramp-up rate to peak*)			2	3	K/s
T_{Smax} to T_{P}					
Liquidus temperature	T_L		217		°C
Time above liquidus temperature	$t_{\scriptscriptstyle \perp}$		80	100	S
Peak temperature	T_{P}		245	260	°C
Time within 5 °C of the specified peak	t _P	10	20	30	S
temperature T _P - 5 K					
Ramp-down rate*			3	6	K/s
T _P to 100 °C					
Time				480	S
25 °C to T _P					

All temperatures refer to the center of the package, measured on the top of the component



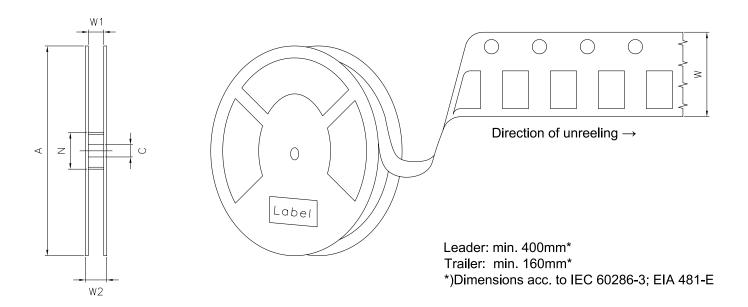
 $^{^{\}ast}$ slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

Taping 6)



C63062-A0223-B12-02

Tape and Reel 7)



Reel Dimensions

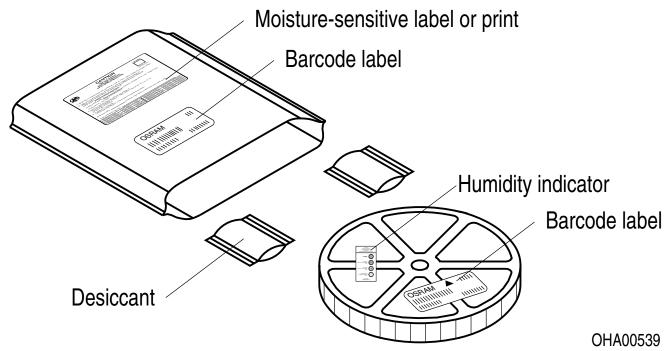
Α	W	N_{\min}	W ₁	W_{2max}	Pieces per PU
180 mm	12 + 0.3 / - 0.1 mm	60 mm	12.4 + 2 mm	18.4 mm	3000



Barcode-Product-Label (BPL)



Dry Packing Process and Materials 6)



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into the class exempt group (exposure time 10000 s). Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

This device is designed for specific/recommended applications only. Please consult OSRAM Opto Semiconductors Sales Staff in advance for detailed information on other non-recommended applications (e.g. automotive).

Change management for this component is aligned with the requirements of the lighting market.

For further application related information please visit www.osram-os.com/appnotes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.



Glossary

- Brightness: Brightness values are measured during a current pulse of typically 10 ms, with a tolerance of +/- 7%.
- Wavelength: The wavelength is measured at a current pulse of typically 10 ms, with a tolerance of ± 0.5 nm
- Forward Voltage: The Forward voltage is measured during a current pulse duration of typically 1 ms with a tolerance of ± 0.05 V.
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- ⁵⁾ **Characteristic curve:** In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- ⁷⁾ **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



GR PSLM31.23

Revision History				
Version	Date	Change		
1.1	2019-04-22	New Layout Electro - Optical Characteristics (Diagrams) Recommended Solder Pad		
1.2	2019-12-08	Schematic Transportation Box Dimensions of Transportation Box		



Published by OSRAM Opto Semiconductors Gml Leibnizstraße 4, D-93055 Regensburg www.osram-os.com © All Rights Reserved.

Published by OSRAM Opto Semiconductors GmbH EU RoHS and China RoHS compliant product

此产品符合欧盟 RoHS 指令的要求; 按照中国的相关法规和标准,不含有毒有害物质或元素。



